

# Electronic Devices

## Mid Term Lecture - 06

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Reference book:

**Electronic Devices and Circuit Theory (Chapter-2)**

Robert L. Boylestad and L. Nashelsky , (11<sup>th</sup> Edition)



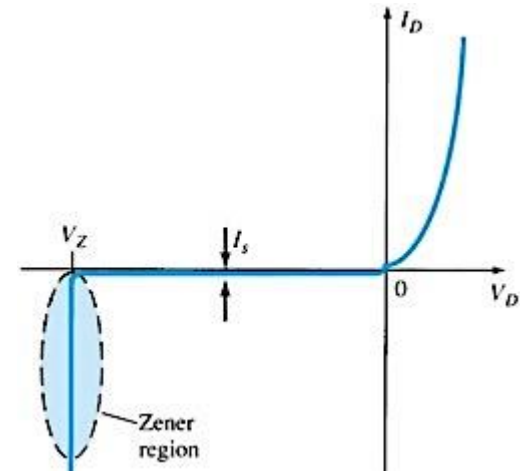
# Objectives

- Become familiar with the analysis of and the range of applications for Zener diodes.



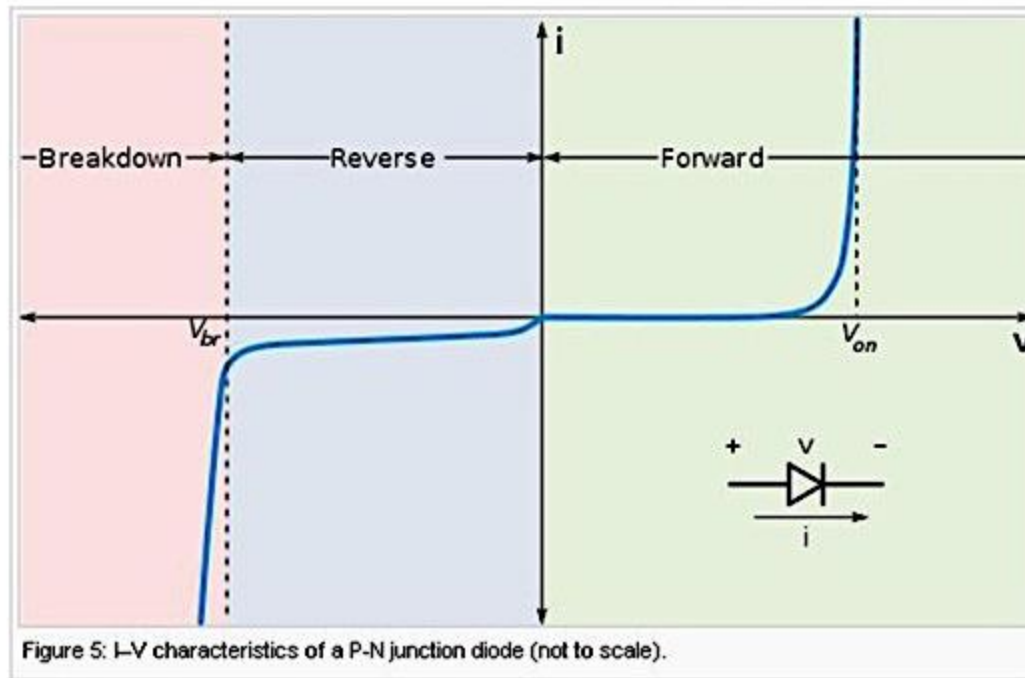
# ZENER REGION

- If the *Diode is reverse biased and the voltage is increased*, a point will be reached when *the diode enters reverse breakdown* and current will flow with a very rapid rate.
- The direction of this current will be opposite to that of the positive voltage region.
- The reverse bias potential that results in *this dramatic change in characteristics* is called the **Zener Potential /Voltage** and is given by the symbol  $V_z$ .
- *The reverse or Avalanche breakdown* is often termed **as Zener Breakdown (at very low levels)**.
- The region where this sharp change in characteristics occur is known as **Zener or Avalanche breakdown region** and the current is termed as avalanche current.



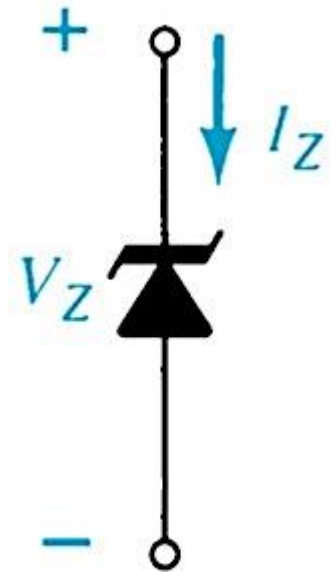
# ZENER REGION

- The maximum reverse-bias potential that can be applied before entering the Zener Region is called the peak inverse voltage (referred to simply as the PIV rating) or the peak reverse voltage (denoted by PRV rating).



# ZENER DIODE

- Diodes that employ the dramatic characteristics of a p-n junction are called Zener Diodes.
- Therefore, a Zener diode operates in reverse bias.
- Common Zener Voltages: 1.8V to 200V.

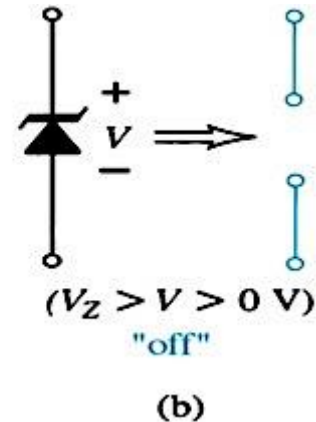
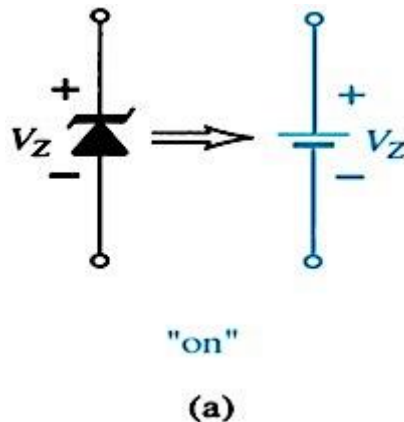


(a)



# ZENER DIODE

- The state of the diode must be determined followed by a substitution of the appropriate model and a determination of the unknown quantities of the network.
- The **off state** is defined by a voltage **less than  $V_Z$  but greater than 0V**. The Zener equivalent is the open circuit.



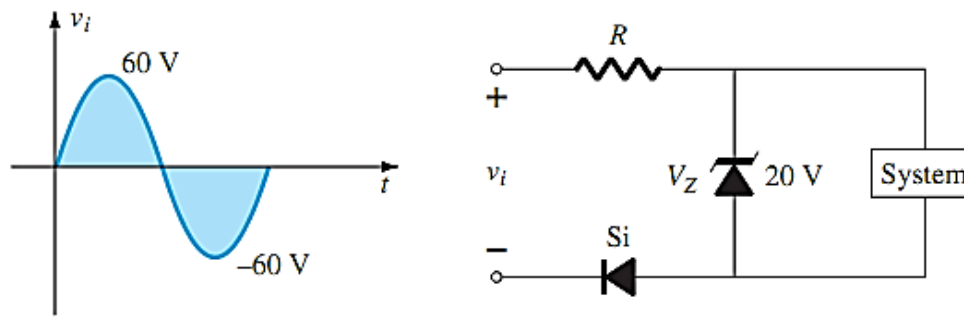
# ZENER DIODE

- The Zener diode is a heavily doped diode which, as a result of doping, has a very narrow depletion region. This allows the diode to be operated in the reverse biased region of the characteristic curve without damaging the PN junction.
- “**Zener Effect**”: The area of Zener diode operation ( $<5V$ ) where the Diode maintains a constant voltage output while operating reverse biased.
- “**Avalanche Effect**”:  $>5V$  applied to the diode while reverse biased which tends to cause the diode to eventually breakdown due to heat generation within the lattice structure of the crystal.
- Because of its higher temperature and current capability, silicon is usually preferred in manufacture of Zener Diodes.
- Zener Diodes provide a stable reference voltage for use in power supplies, voltmeter & other instruments, voltage regulators.



## ZENER DIODE EXAMPLE

**EXAMPLE 2.25** The network of Fig. 2.110 is designed to limit the voltage to 20 V during the positive portion of the applied voltage and to 0 V for a negative excursion of the applied voltage. Check its operation and plot the waveform of the voltage across the system for the applied signal. Assume the system has a very high input resistance so it will not affect the behavior of the network.

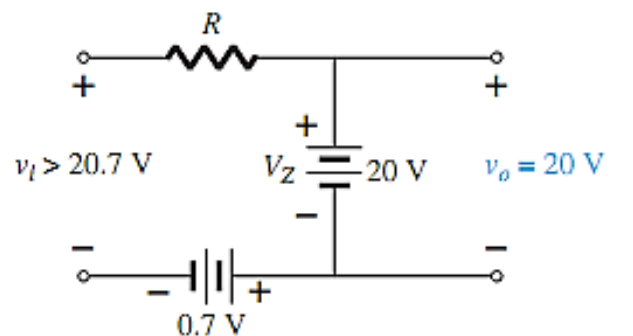


**FIG. 2.110**

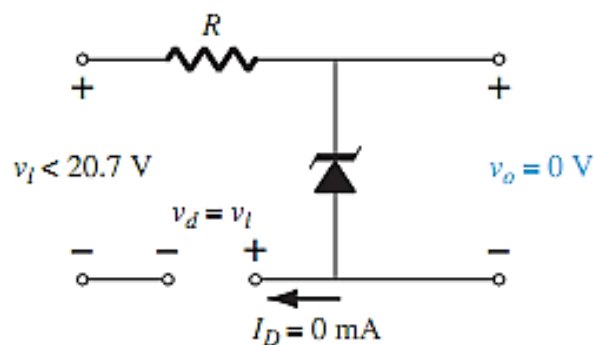
*Controlling network for Example 2.25.*



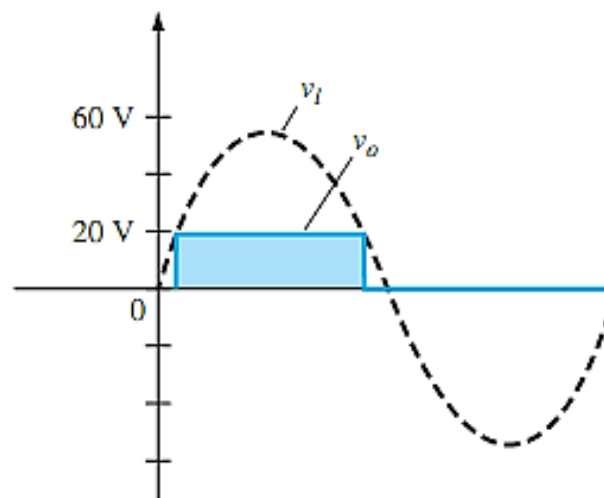
# ZENER DIODE EXAMPLE



(a)



(b)



(c)

**FIG. 2.111**

Response of the network of Fig. 2.110 to the application of a  $60\text{-V}$  sinusoidal signal.

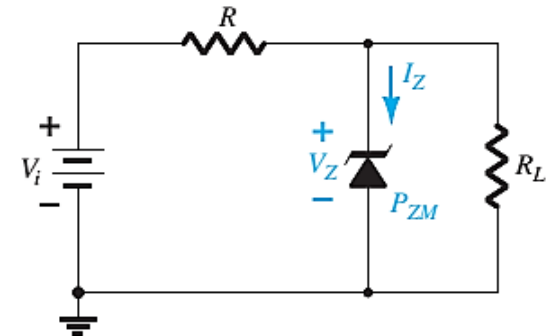
## 1<sup>st</sup> CONDITION: $V_i$ AND $R$ FIXED

- The simplest of Zener diode regulator networks appears in Fig. 2.112. The applied dc voltage is fixed, as is the load resistor. The analysis can fundamentally be broken down into two steps.

1. Determine the state of the Zener diode by removing it from the network and calculating the voltage across the resulting open circuit.

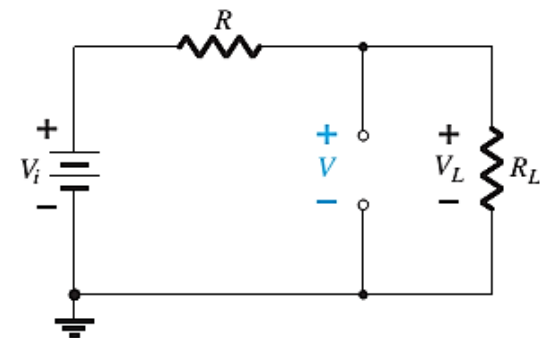
$$V = V_L = \frac{R_L V_i}{R + R_L}$$

- If  $V \geq V_Z$ , the Zener diode is on, and the appropriate equivalent model can be substituted.
- If  $V < V_Z$ , the diode is off, and the open-circuit equivalence is substituted.



**FIG. 2.112**

*Basic Zener regulator.*



**FIG. 2.113**

*Determining the state of the Zener diode.*

# 1<sup>st</sup> CONDITION: $V_i$ AND $R$ FIXED

2. Substitute the appropriate equivalent circuit and solve for the desired unknowns.

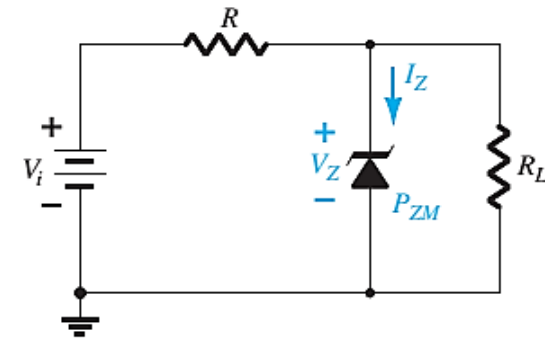
For the network of Fig. 2.112, the “on” state will result in the equivalent network of Fig. 2.114. Since voltages across parallel elements must be the same, we find that

$$\boxed{V_L = V_Z} \quad \boxed{I_Z = I_R - I_L} \quad I_L = \frac{V_L}{R_L} \quad \text{and} \quad I_R = \frac{V_R}{R} = \frac{V_i - V_L}{R}$$

- The power dissipated by the Zener diode is determined by

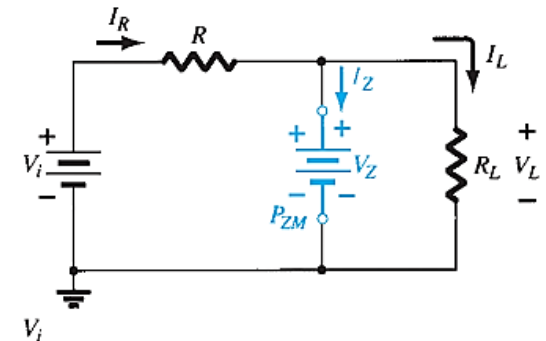
$$\boxed{P_Z = V_Z I_Z}$$

That must be less than the  $P_{ZM}$  specified for the device.



**FIG. 2.112**

*Basic Zener regulator.*



**FIG. 2.114**

*Substituting the Zener equivalent for the “on” situation.*

# 1<sup>st</sup> CONDITION: $V_i$ AND $R$ FIXED

## EXAMPLE 2.26

- For the Zener diode network of Fig. 2.115, determine  $V_L$ ,  $V_R$ ,  $I_Z$ , and  $P_Z$ .
- Repeat part (a) with  $R_L = 3 \text{ k}\Omega$ .

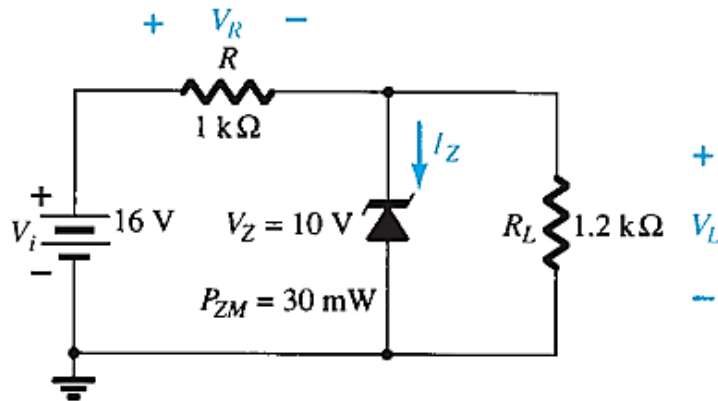


FIG. 2.115

Zener diode regulator for Example 2.26.

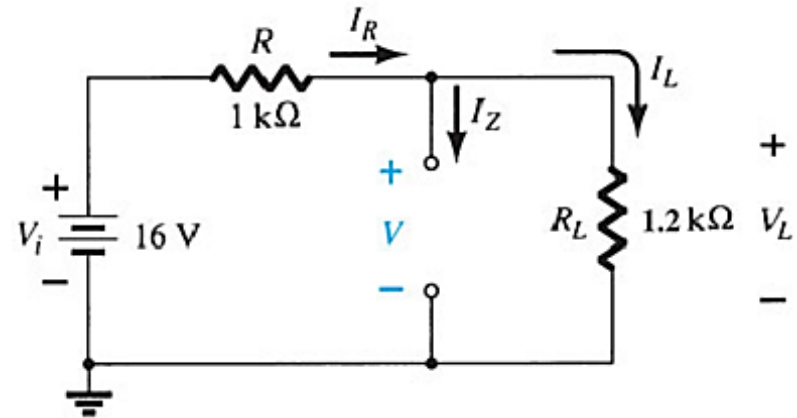


FIG. 2.116

Determining  $V$  for the regulator of Fig. 2.115.

$$V = \frac{R_L V_i}{R + R_L} = \frac{1.2 \text{ k}\Omega (16 \text{ V})}{1 \text{ k}\Omega + 1.2 \text{ k}\Omega} = 8.73 \text{ V}$$

## 1<sup>st</sup> CONDITION: $V_i$ AND $R$ FIXED

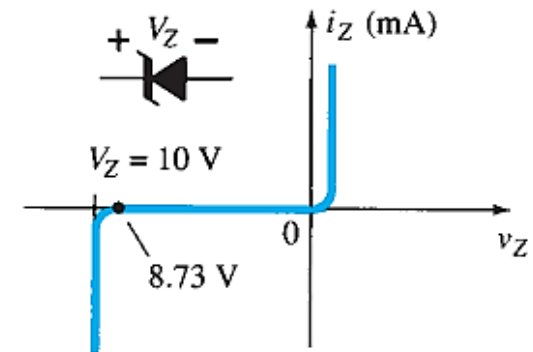
Since  $V = 8.73$  V is less than  $V_Z = 10$  V, the diode is in the “off” state.

$$V_L = V = 8.73 \text{ V}$$

$$V_R = V_i - V_L = 16 \text{ V} - 8.73 \text{ V} = 7.27 \text{ V}$$

$$I_Z = 0 \text{ A}$$

$$P_Z = V_Z I_Z = V_Z(0 \text{ A}) = 0 \text{ W}$$



**FIG. 2.117**

*Resulting operating point for the network of Fig. 2.115.*

b. Applying Eq. (2.16) results in

$$V = \frac{R_L V_i}{R + R_L} = \frac{3 \text{ k}\Omega(16 \text{ V})}{1 \text{ k}\Omega + 3 \text{ k}\Omega} = 12 \text{ V}$$

Since  $V = 12$  V is greater than  $V_Z = 10$  V, the diode is in the “on” state

## 1<sup>st</sup> CONDITION: $V_i$ AND $R$ FIXED

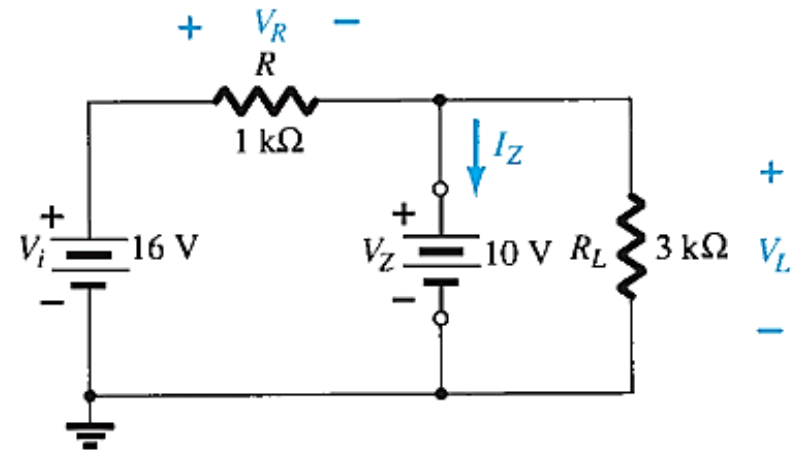
$$V_L = V_Z = 10 \text{ V}$$

$$V_R = V_i - V_L = 16 \text{ V} - 10 \text{ V} = 6 \text{ V}$$

$$I_L = \frac{V_L}{R_L} = \frac{10 \text{ V}}{3 \text{ k}\Omega} = 3.33 \text{ mA}$$

$$I_R = \frac{V_R}{R} = \frac{6 \text{ V}}{1 \text{ k}\Omega} = 6 \text{ mA}$$

$$\begin{aligned} I_Z &= I_R - I_L \text{ [Eq. (2.18)]} \\ &= 6 \text{ mA} - 3.33 \text{ mA} \\ &= 2.67 \text{ mA} \end{aligned}$$



**FIG. 2.118**

Network of Fig. 2.115 in the “on” state.

The power dissipated is

$$P_Z = V_Z I_Z = (10 \text{ V})(2.67 \text{ mA}) = 26.7 \text{ mW}$$

which is less than the specified  $P_{ZM} = 30 \text{ mW}$ .



## 2<sup>nd</sup> CONDITION: FIXED $V_i$ , VARIABLE $R_L$

- Due to the offset voltage  $V_z$ , there is a specific range of resistor values (and therefore load current) which will ensure that the Zener diode is in the on state.
- Too small  $R_L \rightarrow V_L < V_z \rightarrow$  Zener diode will be in the off state.
- To determine the min  $R_L$  that will turn the Zener diode on :

$$R_{L_{\min}} = \frac{RV_Z}{V_i - V_Z}$$

$$V_L = V_Z = \frac{R_L V_i}{R_L + R}$$

- Any load resistance value greater than the  $R_L$  min will ensure that the Zener diode is in the on state and the diode can be replaced by its  $V_z$  source equivalent.
- The max  $I_L$

$$I_{L_{\max}} = \frac{V_L}{R_L} = \frac{V_Z}{R_{L_{\min}}}$$



## 2<sup>nd</sup> CONDITION: FIXED $V_i$ , VARIABLE $R_L$

- Once the diode is in the on state, the voltage across R remains fixed at:

$$V_R = V_i - V_Z$$

$$I_R = \frac{V_R}{R}$$

$$I_Z = I_R - I_L$$

- $I_Z$  is limited to  $I_{ZM}$  as provided on the data sheet, it does affect the range of  $R_L$  and therefore  $I_L$ .

$$I_{L_{\min}} = I_R - I_{ZM}$$

- The maximum load resistance

$$R_{L_{\max}} = \frac{V_Z}{I_{L_{\min}}}$$

- See Example 2.27.*





### 3<sup>rd</sup> CONDITION: FIXED $R_L$ , VARIABLE $V_i$

- For fixed values of  $R_L$ , the voltage  $V_i$  must be sufficiently large to turn the Zener diode on. The min turn-on voltage  $V_i = V_{i\min}$ :

$$V_{i\min} = \frac{(R_L + R)V_Z}{R_L}$$

- The max  $V_L = V_Z = \frac{R_L V_i}{R_L + R}$  by the max Zener current  $I_{ZM}$ .

$$I_{R\max} = I_{ZM} + I_L$$

- Since  $I_L$  is fixed at  $V_Z/R_L$  and  $I_{ZM}$  is the max value of  $I_Z$ , the max  $V_i$  is defined by:

$$V_{i\max} = V_{R\max} + V_Z$$

$$V_{i\max} = I_{R\max} R + V_Z$$



### 3<sup>rd</sup> CONDITION: FIXED $R_L$ , VARIABLE $V_i$

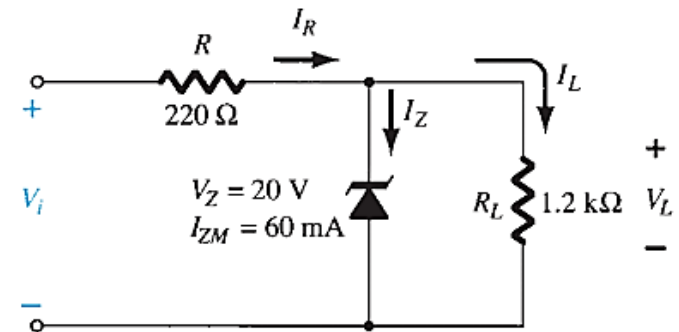
**EXAMPLE 2.28** Determine the range of values of  $V_i$  that will maintain the Zener diode of Fig. 2.121 in the “on” state.

$$V_{i_{\min}} = \frac{(R_L + R)V_Z}{R_L} = \frac{(1200\ \Omega + 220\ \Omega)(20\ \text{V})}{1200\ \Omega} = 23.67\ \text{V}$$

$$I_L = \frac{V_L}{R_L} = \frac{V_Z}{R_L} = \frac{20\ \text{V}}{1.2\ \text{k}\Omega} = 16.67\ \text{mA}$$

$$\begin{aligned} I_{R_{\max}} &= I_{ZM} + I_L = 60\ \text{mA} + 16.67\ \text{mA} \\ &= 76.67\ \text{mA} \end{aligned}$$

$$\begin{aligned} V_{i_{\max}} &= I_{R_{\max}}R + V_Z \\ &= (76.67\ \text{mA})(0.22\ \text{k}\Omega) + 20\ \text{V} \\ &= 16.87\ \text{V} + 20\ \text{V} \\ &= 36.87\ \text{V} \end{aligned}$$



**FIG. 2.121**

*Regulator for Example 2.28.*



# Thank You

